

L Number	Hits	Search Text	DB	Time stamp
1	3132	over\$1voltage adj protection	USPAT; US-PGPUB	2004/08/12 17:11
2	232	trench\$2 near2 DMOS	USPAT; US-PGPUB	2004/08/12 17:11
3	181831	cathode\$1	USPAT; US-PGPUB	2004/08/12 17:11
4	123939	anode\$1	USPAT; US-PGPUB	2004/08/12 17:12
5	48869	trench\$2	USPAT; US-PGPUB	2004/08/12 17:12
6	2337	DMOS	USPAT; US-PGPUB	2004/08/12 17:12
7	3	(over\$1voltage adj protection) and cathode\$1 and	USPAT; US-PGPUB	2004/08/12 17:39
10	256329	anode\$1 and trench\$2 and DMOS diode	USPAT; US-PGPUB	2004/08/12 17:39
11	4	(over\$1voltage adj protection) and trench\$2 and	USPAT; US-PGPUB	2004/08/12 17:40
12	31	DMOS and diode (over\$1voltage adj protection) and DMOS and	USPAT; US-PGPUB	2004/08/12 17:44
14	5157	diode vertical adj channel	USPAT; US-PGPUB	2004/08/12 17:46
15	428805	gate\$1	USPAT; US-PGPUB	2004/08/12 17:47
16	0	(over\$1voltage adj protection) and diode and	USPAT; US-PGPUB	2004/08/12 17:48
17	8	(trench\$2 same (vertical adj channel) same gate\$1)	USPAT; US-PGPUB	2004/08/12 18:02
19	200	diode and (trench\$2 same (vertical adj channel) same gate\$1)	USPAT; US-PGPUB	2004/08/12 18:25
20	14	438/237.ccls.	USPAT; US-PGPUB	2004/08/12 18:39
21	1565	438/156,212,268-272,589.ccls.	USPAT; US-PGPUB	2004/08/12 18:40
22	301622	diode\$1	USPAT; US-PGPUB	2004/08/12 18:41
23	2021	excess adj voltage	USPAT; US-PGPUB	2004/08/12 18:41
24	281	438/156,212,268-272,589.ccls. and (over\$1voltage adj protection) or diode\$1 or (excess adj voltage))	USPAT; US-PGPUB	2004/08/12 18:42